



BDX 62, A, B, C

PNP SILICON DARLINGTONS

General purpose darlingtonts designed for power amplifier and switching applications.

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings		Value	Unit		
V_{CEO}	Collector-Emitter Voltage		BDX62 -60	V		
			BDX62A -80			
			BDX62B -100			
			BDX62C -120			
V_{CEV}	Collector-Emitter Voltage	$V_{BE} = -1.5 \text{ V}$	BDX62 -60	V		
			BDX62A -80			
			BDX62B -100			
			BDX62C -120			
V_{EBO}	Emitter-Base Voltage		BDX62 BDX62A BDX62B BDX62C -5.0	V		
I_C	Collector Current	$I_{C(RMS)}$	BDX62 BDX62A BDX62B BDX62C -8	A		
			I_{CM}		BDX62 BDX62A BDX62B BDX62C -12	
I_B	Base Current		BDX62 BDX62A BDX62B BDX62C -0.15	A		
P_T	Power Dissipation	@ $T_C = 25^\circ$	BDX62 BDX62A BDX62B BDX62C 90	Watts W/°C		

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Symbol	Ratings	Value	Unit
T_J	Junction Temperature	-55 to +200	°C
T_S	Storage Temperature		

THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJ-c}	Thermal Resistance, Junction to Case	1.94	°C/W

ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit	
$V_{CEO(SUS)}$	Collector-Emitter Breakdown Voltage (*)	$I_C=-0.1\text{ A}, I_B=0, L=25\text{mH}$	BDX62	-60	-	-	V
			BDX62A	-80	-	-	
			BDX62B	-100	-	-	
			BDX62C	-120	-	-	

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Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit	
I_{CEO}	Collector Cutoff Current	$V_{CE}=-30\text{ V}$	BDX62	-	-	-0.5	mA
		$V_{CE}=-40\text{ V}$	BDX62A	-	-		
		$V_{CE}=-50\text{ V}$	BDX62B	-	-		
		$V_{CE}=-60\text{ V}$	BDX62C	-	-		
I_{EBO}	Emitter Cutoff Current	$V_{BE}=-5\text{ V}$	BDX62 BDX62A BDX62B BDX62C	-	-	-5.0	mA
I_{CBO}	Collector-Base Cutoff Current	$V_{CBO}=-60\text{ V}$	BDX62	-	-	-0.2	-
		$V_{CBO}=-60\text{ V}$ $T_{CASE}=150^{\circ}\text{C}$		-	-	-2	
		$V_{CBO}=-80\text{ V}$	BDX62A	-	-	-0.2	
		$V_{CBO}=-80\text{ V}$ $T_{CASE}=150^{\circ}\text{C}$		-	-	-2	
		$V_{CBO}=-100\text{ V}$	BDX62B	-	-	-0.2	

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Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit	
I_{CBO}		$V_{CBO}=-100\text{ V}$ $T_{CASE}=150^{\circ}\text{C}$	BDX62B	-	-	-2	
		$V_{CBO}=-120\text{ V}$		-	-	-0.2	
		$V_{CBO}=-120\text{ V}$ $T_{CASE}=150^{\circ}$	BDX62C	-	-	-2	
$V_{CE(SAT)}$	Collector-Emitter saturation Voltage (*)	$I_C=-3.0\text{ A}$, $I_B=-12\text{ mA}$	BDX62 BDX62A BDX62B BDX62C	-	1.8	-	V
V_F	Forward Voltage (pulse method)	$I_F=3\text{ A}$	BDX62 BDX62A BDX62B BDX62C	-	1500	-2.5	V
V_{BE}	Base-Emitter Voltage (*)	$I_C=-3.0\text{ A}$, $V_{CE}=-3\text{ V}$	BDX62 BDX62A BDX62B BDX62C	-	-	-	V
$F_{h_{21e}}$	Forward current transfer ratio Cutoff frequency	$V_{CE}=3\text{ V}$, $I_C=3\text{ A}$	BDX62 BDX62A BDX62B BDX62C	-	60	-	kHz
f_T	Transition Frequency	$V_{CE}=-3\text{ V}$, $I_C=-3\text{ A}$, $f=1\text{ MHz}$	BDX62 BDX62A BDX62B BDX62C	-	7	-	MHz
h_{21E}	Static forward current transfer ratio (*)	$V_{CE}=-3\text{ V}$, $I_C=-0.5\text{ A}$	BDX62 BDX62A BDX62B BDX62C	1000	750	-	
		$V_{CE}=-3\text{ V}$, $I_C=-3\text{ A}$	BDX62 BDX62A BDX62B BDX62C	-	-	-	
		$V_{CE}=-3\text{ V}$, $I_C=-8\text{ A}$					

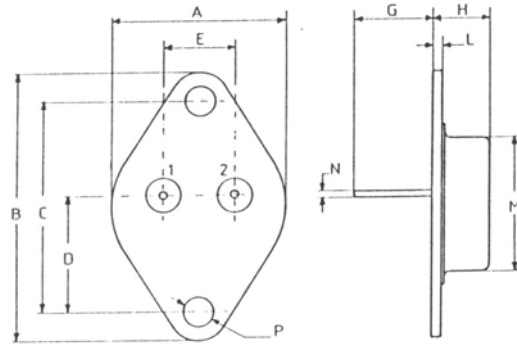
(*) Pulse Width $\approx 300\text{ }\mu\text{s}$, Duty Cycle $\angle 2.0\%$

(1) collector-Emitter voltage limited et $V_{CEci} = V_{\text{rated}}$ by an auxiliary circuit

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MECHANICAL DATA CASE TO-3

DIMENSIONS		
	mm	inches
A	25,51	1,004
B	38,93	1,53
C	30,12	1,18
D	17,25	0,68
E	10,89	0,43
G	11,62	0,46
H	8,54	0,34
L	1,55	0,6
M	19,47	0,77
N	1	0,04
P	4,06	0,16



Pin 1 :	Base
Pin 2 :	Emitter
Case :	Collector